

IPL60R185P7AUMA1

IPL60R185P7AUMA1 Information

Heisener.com	 IPL60R185P7AUMA1 Infineon Technologies Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single MOSFET N-CH 650V 19A VSON-4 4-PowerTSFN For the pricing/inventory/lead time, please contact	
For Reference Only	us Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



IPL60R185P7AUMA1 Specifications

Manufacturer Part Number	IPL60R185P7AUMA1
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	4-PowerTSFN
Series	CoolMOS? P7
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	650V
Current - Continuous Drain (Id) @ 25°C	19A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	4V @ 280µA
Gate Charge (Qg) (Max) @ Vgs	25nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	1081pF @ 400V
Vgs (Max)	$\pm 20 V$
FET Feature	-
Power Dissipation (Max)	81W (Tc)
Rds On (Max) @ Id, Vgs	185 mOhm @ 5.6A, 10V
Operating Temperature	-40°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	PG-VSON-4
Package / Case	4-PowerTSFN
	Report errors?

IPL60R185P7AUMA1 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

IPL60R185P7AUMA1 Payment Methods





If you have any question about IPL60R185P7AUMA1, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com